

General description

Symbol	Value
V_R	Min 1200V
I_F	8A
Q_C	Typ 53nC

Features

- 175°C Maximum operating temperature
- Negligible reverse recovery current.
- Fast switching speed

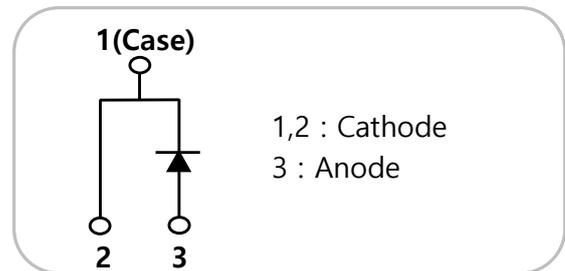
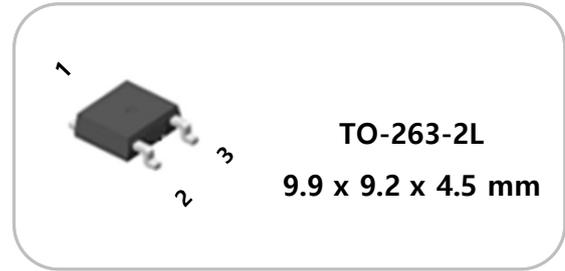
Applications

- General purpose
- Switching mode power supply
- Boot diodes in PFC at DC/DC
- Industrial motor drives
- Motor drivers
- Solar inverters

Maximum ratings ($T_C = 25^\circ\text{C}$)

Parameter	Symbol	Test condition	Value	Units
Repetitive peak reverse voltage	V_{RRM}	-	1200	V
DC peak reverse voltage	V_R	-	1200	V
Continuous forward current	I_F	$T_C=150^\circ\text{C}$	8	A
Non-repetitive forward surge current	I_{FSM}	$T_C=25^\circ\text{C}, t_p=10\text{ms}$	61	A
Power dissipation	P_D	$T_C=25^\circ\text{C}$	165	W
Operating and storage temperature range	T_j, T_{stg}	-	-55 to 175	$^\circ\text{C}$

Package

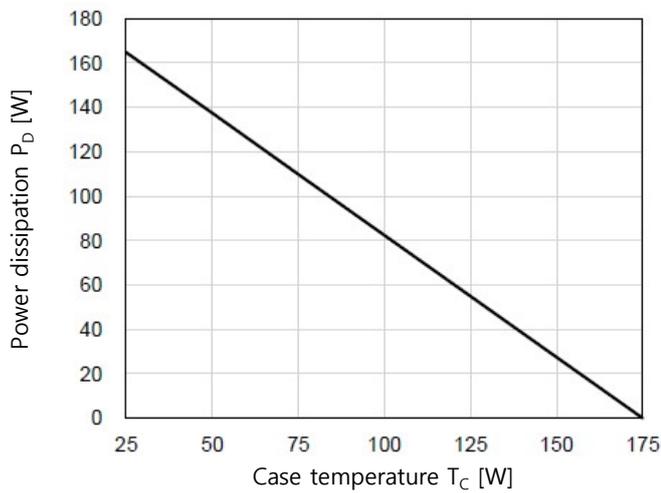
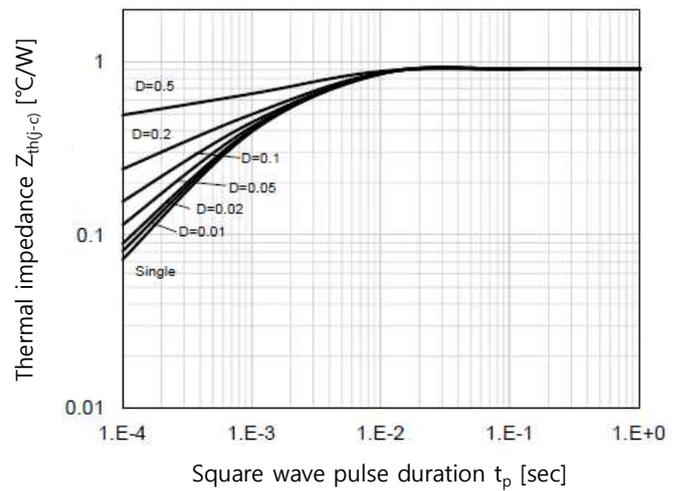


Electrical characteristics ($T_C = 25^\circ\text{C}$)

Parameter	Symbol	Test condition	Value			Units
			Min	Typ	Max	
Forward voltage	V_F	$I_F=8\text{A}, T_C=25^\circ\text{C}$	-	1.40	1.70	V
		$I_F=8\text{A}, T_C=175^\circ\text{C}$	-	1.80	-	V
Reverse current	I_R	$V_R=1200\text{V}, T_C=25^\circ\text{C}$	-	-	100	μA
		$V_R=1200\text{V}, T_C=175^\circ\text{C}$	-	-	300	μA
Total capacitive charge	Q_C	$V_R=800\text{V}$	-	53	-	nC
Total capacitance	C	$V_R=1\text{V}, f=100\text{kHz}$	-	582	-	pF
		$V_R=800\text{V}, f=100\text{kHz}$	-	35	-	pF

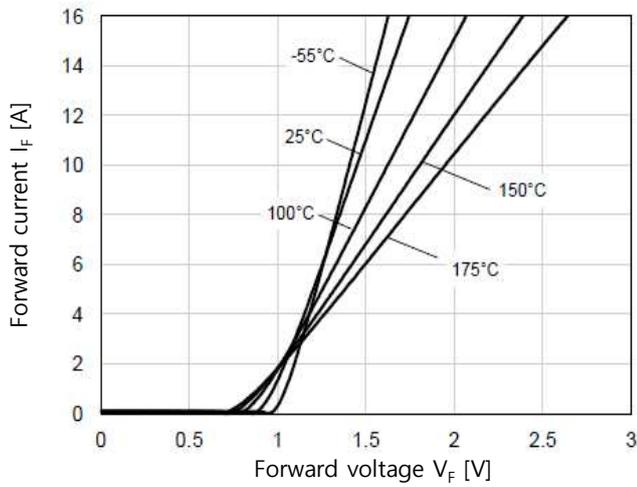
Thermal characteristics ($T_C = 25^\circ\text{C}$)

Symbol	Parameter	Typ	Max	Units
$R_{th(j-c)}$	Junction to case	-	0.91	$^\circ\text{C}/\text{W}$

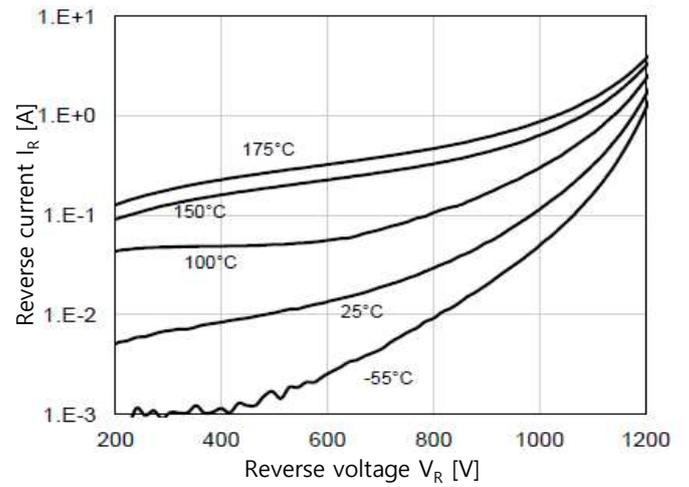
 $T_C - P_D$ Characteristics

 $t_p - Z_{th(j-c)}$ Characteristics


Typical electrical characteristics curves ($T_C = 25^\circ\text{C}$)

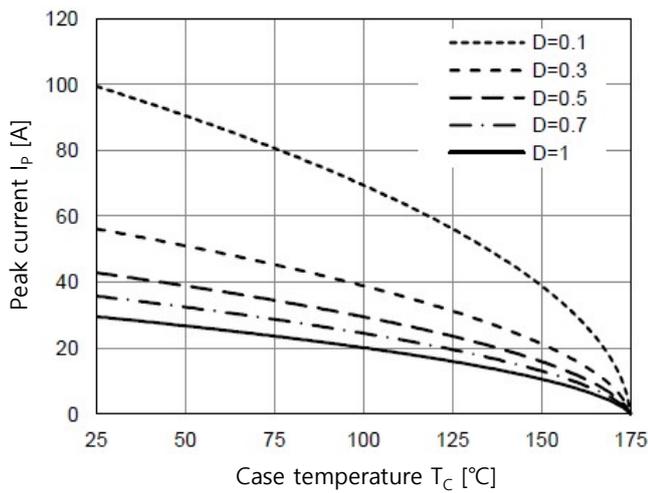
$V_F - I_F$ Characteristics



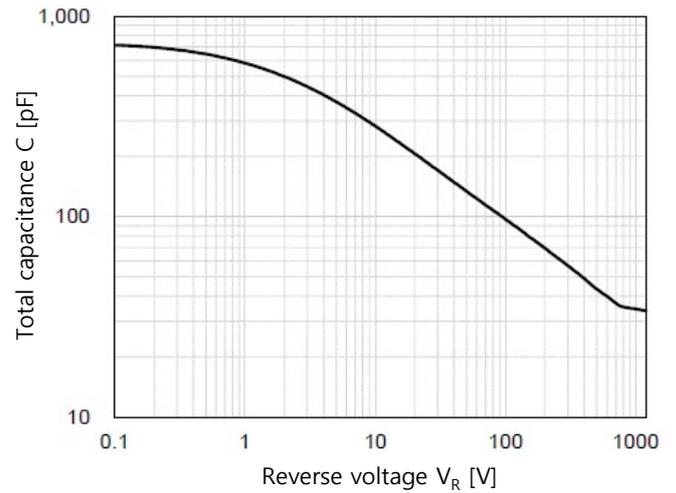
$V_R - I_R$ Characteristics



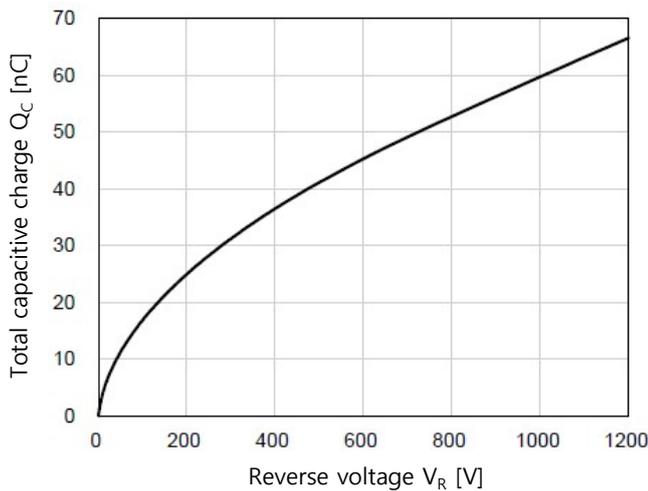
$T_C - I_P$ Characteristics



$V_R - C$ Characteristics

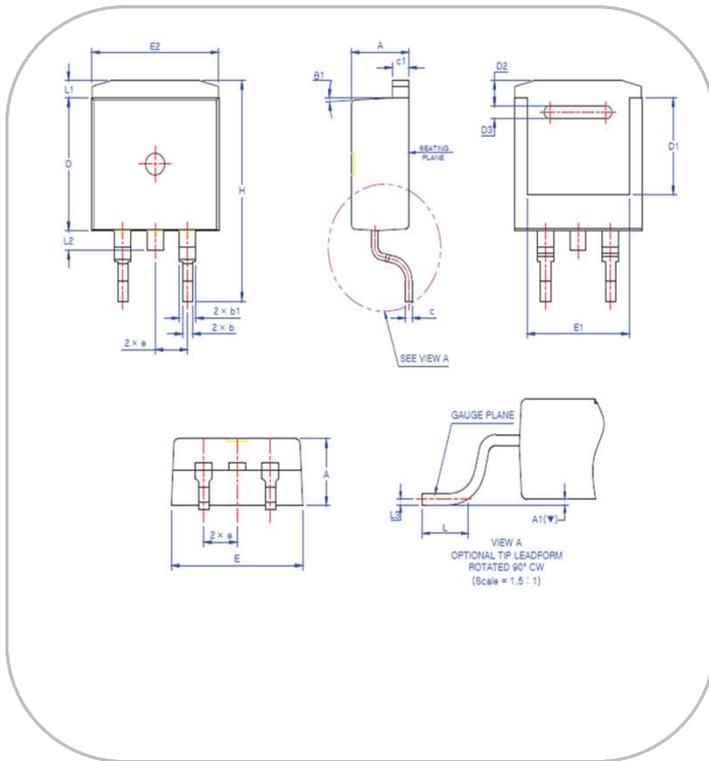


$V_R - Q_C$ Characteristics



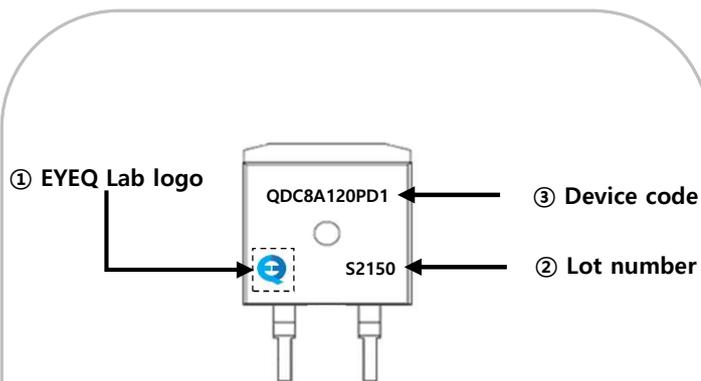
Package dimensions(TO-263)

[Unit : mm]



Symbol	Min	Typ	Max
A	4.30	4.50	4.70
A1(▼)	0.00	-	0.25
b	0.70	0.80	0.90
b1	1.17	1.27	1.37
c	0.45	0.50	0.60
c1	1.25	1.30	1.40
D	9.00	9.20	9.40
D1	6.50	6.70	6.90
D2	1.65	1.75	1.85
D3	0.80	0.90	1.00
E	9.80	10.00	10.20
E1	7.80	8.00	8.20
E2	9.70	9.90	10.10
e	2.54 BSC		
H	15.00	15.30	15.60
L	2.00	2.30	2.60
L1	1.00	1.20	1.40
L2	1.20	1.40	1.60
L3	0.254 BSC		
θ1	(3°)		

Marking information



- ① Company logo
- ② Lot number : 23 – 2023 Year , 04 – 04 Week
- ③ Device code : Q – EYEQ Lab, D – Diode,
8A – 8A, 120 – 1200V

